



High-order DBR semiconductor lasers: effect of grating parameters on grating performance: publisher's note

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In Ref. [1], a coauthor's name was corrected. The paper was corrected online on 2 October 2020.

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REFERENCE

1. S. E, Y. Zhou, X. Zhang, J. Zhang, Y. Huang, Y. Zeng, J. Cui, Y. Liu, Y. Ning, and L. Wang, "High-order DBR semiconductor lasers: